

2SK3310

Switching Regulator Applications

- Low drain-source ON resistance: $R_{DS(ON)} = 0.48 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.3 S$ (typ.)
- Low leakage current: $I_{DSS} = 100 \mu A$ (max) ($V_{DS} = 450 V$)
- Enhancement-model: $V_{th} = 3.0 \sim 5.0 V$ ($V_{DS} = 10 V, I_D = 1 mA$)

Maximum Ratings ($T_a = 25^\circ C$)

| Characteristics | | Symbol | Rating | Unit |
|--|----------------|-----------|----------------|------------|
| Drain-source voltage | | V_{DSS} | 450 | V |
| Drain-gate voltage ($R_{GS} = 20 k\Omega$) | | V_{DGR} | 450 | V |
| Gate-source voltage | | V_{GSS} | ± 30 | V |
| Drain current | DC (Note 1) | I_D | 10 | A |
| | Pulse (Note 1) | I_{DP} | 40 | |
| Drain power dissipation ($T_c = 25^\circ C$) | | P_D | 40 | W |
| Single pulse avalanche energy (Note 2) | | E_{AR} | 222 | mJ |
| Avalanche current | | I_{AR} | 10 | A |
| Repetitive avalanche energy (Note 3) | | E_{AR} | 4 | mJ |
| Channel temperature | | T_{ch} | 150 | $^\circ C$ |
| Storage temperature range | | T_{stg} | $-55 \sim 150$ | $^\circ C$ |

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|----------------|-------|--------------|
| Thermal resistance, channel to case | $R_{th(ch-c)}$ | 3.125 | $^\circ C/W$ |
| Thermal resistance, channel to ambient | $R_{th(ch-a)}$ | 62.5 | $^\circ C/W$ |

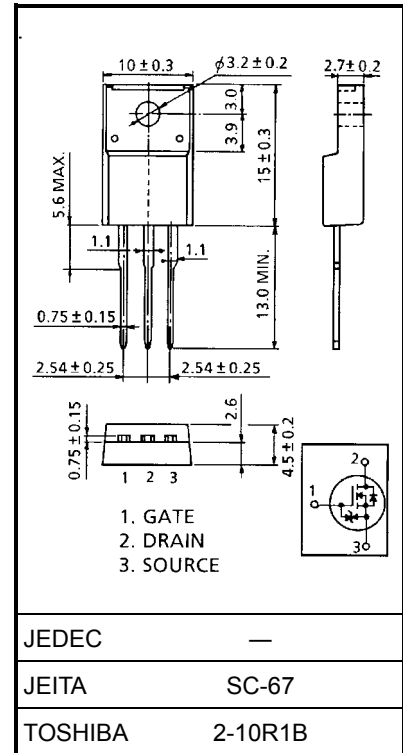
Note 1: Please use devices on conditions that the channel temperature is below $150^\circ C$.

Note 2: $V_{DD} = 90 V, T_{ch} = 25^\circ C$ (initial), $L = 3.7 mH, R_G = 25 \Omega, I_{AR} = 10 A$

Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Unit: mm



Weight: 1.9 g (typ.)

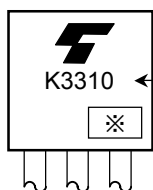
Electrical Characteristics (Ta = 25°C)

| Characteristics | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|---------------|---------------|--|----------|------|----------|---------------|
| Gate leakage current | | I_{GSS} | $V_{GS} = \pm 25\text{ V}, V_{DS} = 0\text{ V}$ | — | — | ± 10 | μA |
| Gate-source breakdown voltage | | $V_{(BR)GSS}$ | $I_G = \pm 10\ \mu\text{A}, V_{DS} = 0\text{ V}$ | ± 30 | — | — | V |
| Drain cut-off current | | I_{DSS} | $V_{DS} = 450\text{ V}, V_{GS} = 0\text{ V}$ | — | — | 100 | μA |
| Drain-source breakdown voltage | | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$ | 450 | — | — | V |
| Gate threshold voltage | | V_{th} | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$ | 3.0 | — | 5.0 | V |
| Drain-source ON resistance | | $R_{DS(ON)}$ | $V_{GS} = 10\text{ V}, I_D = 5\text{ A}$ | — | 0.48 | 0.65 | Ω |
| Forward transfer admittance | | $ Y_{fs} $ | $V_{DS} = 10\text{ V}, I_D = 5\text{ A}$ | 1.5 | 4.3 | — | S |
| Input capacitance | | C_{iss} | $V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | — | 920 | — | pF |
| Reverse transfer capacitance | | C_{rss} | | — | 12 | — | |
| Output capacitance | | C_{oss} | | — | 140 | — | |
| Switching time | Rise time | t_r | | — | 25 | — | ns |
| | Turn-on time | t_{on} | | — | 35 | — | |
| | Fall time | t_f | | — | 10 | — | |
| | Turn-off time | t_{off} | | — | 60 | — | |
| Total gate charge | | Q_g | $V_{DD} \approx 360\text{ V}, V_{GS} = 10\text{ V}, I_D = 10\text{ A}$ | — | 23 | — | nC |
| Gate-source charge | | Q_{gs} | | — | 9 | — | |
| Gate-drain charge | | Q_{gd} | | — | 14 | — | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|------|---------------|
| Continuous drain reverse current (Note 1) | I_{DR} | — | — | — | 10 | A |
| Pulse drain reverse current (Note 1) | I_{DRP} | — | — | — | 40 | A |
| Forward voltage (diode) | V_{DSF} | $I_{DR} = 10\text{ A}, V_{GS} = 0\text{ V}$ | — | — | -1.7 | V |
| Reverse recovery time | t_{rr} | $I_{DR} = 10\text{ A}, V_{GS} = 0\text{ V},$ | — | 280 | — | ns |
| Reverse recovery charge | Q_{rr} | $dI_{DR}/dt = 100\text{ A}/\mu\text{s}$ | — | 2.7 | — | μC |

Marking

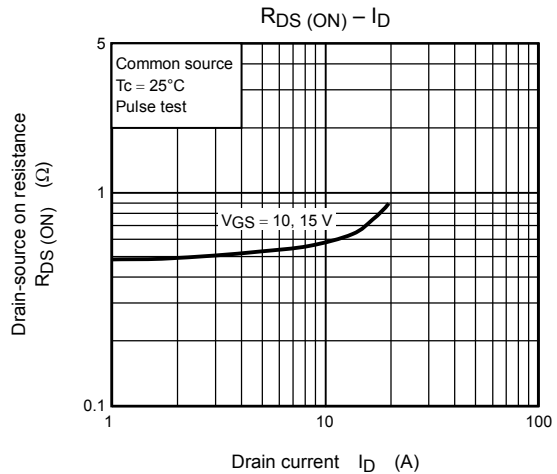
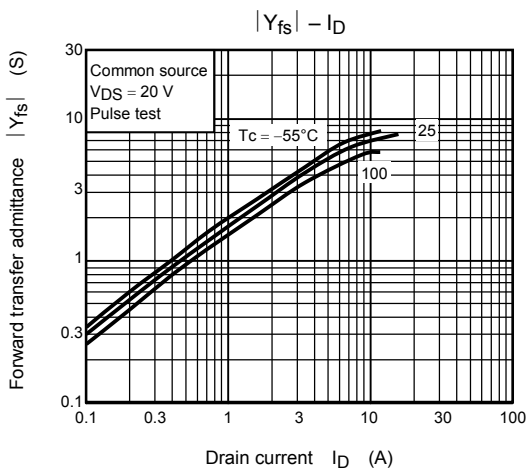
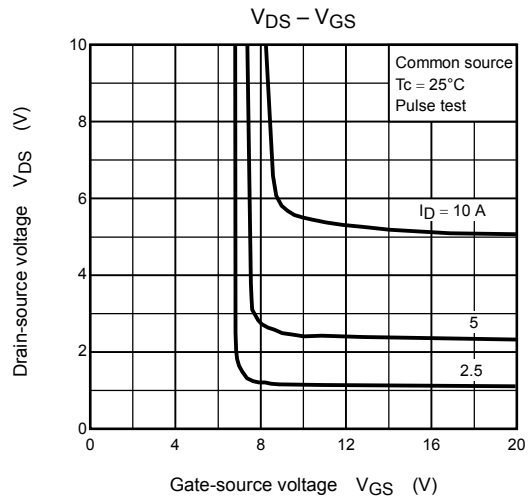
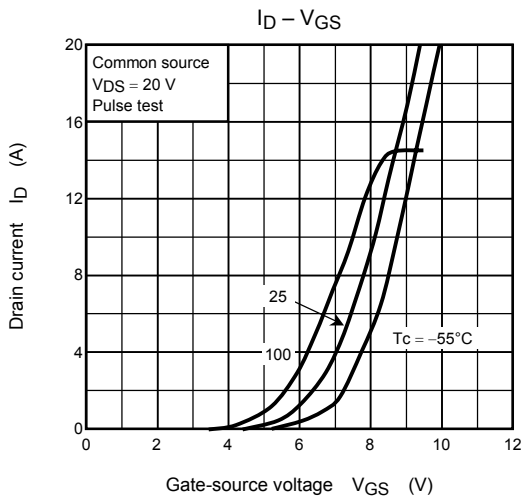
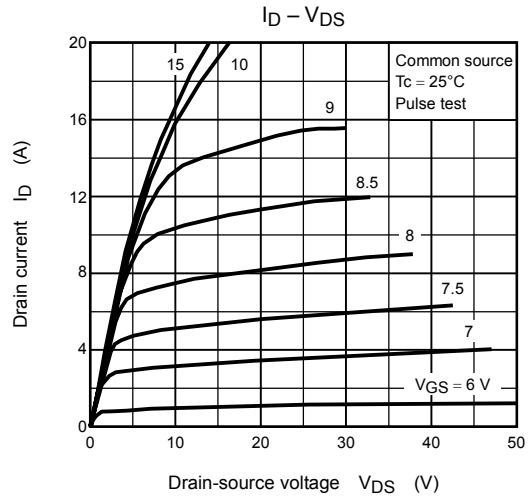
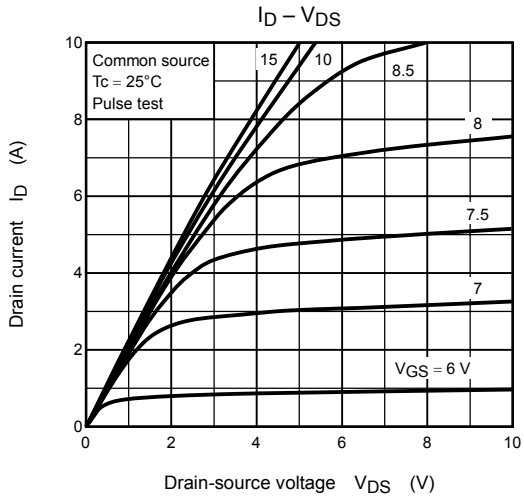


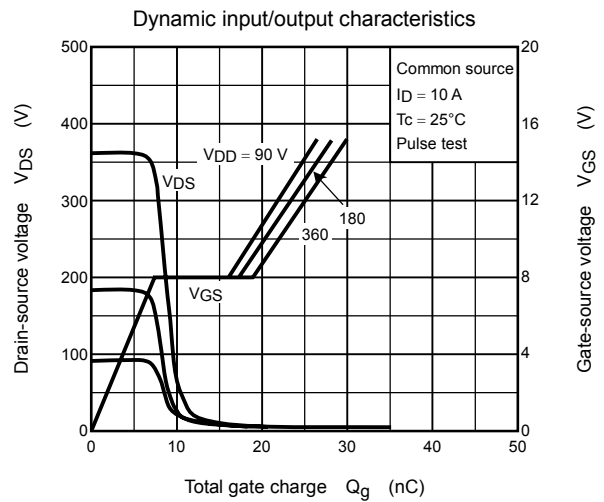
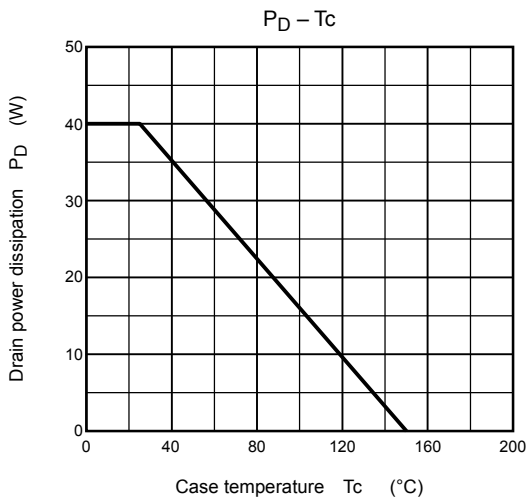
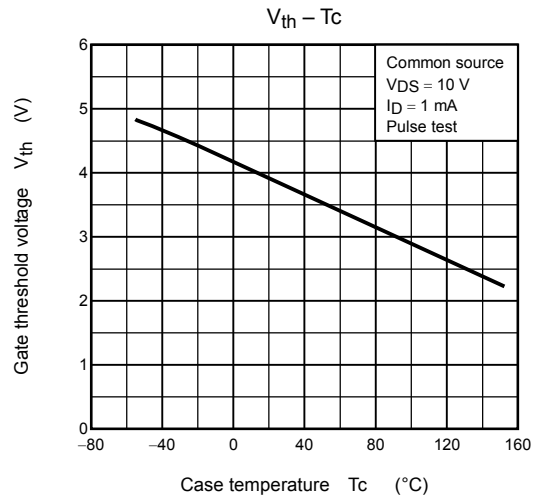
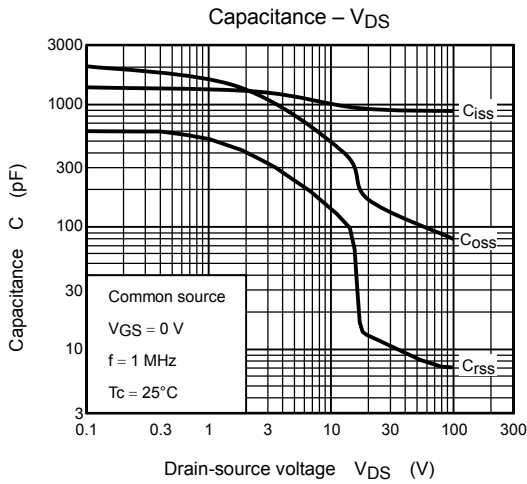
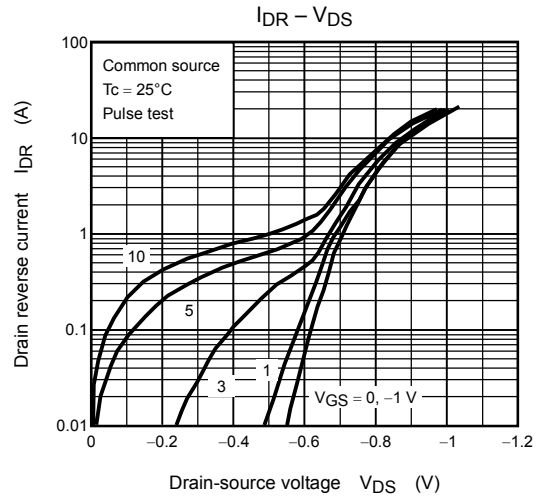
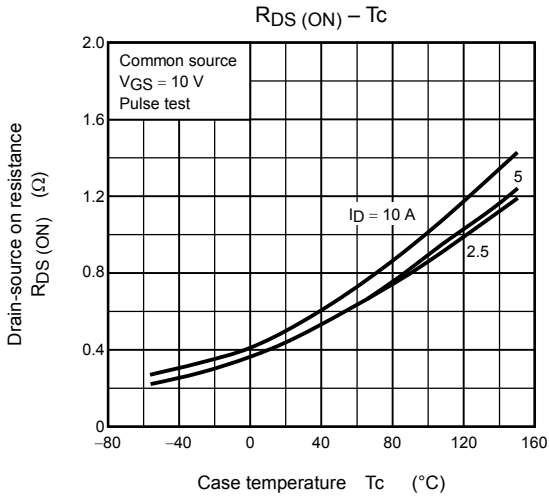
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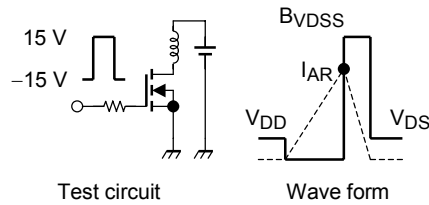
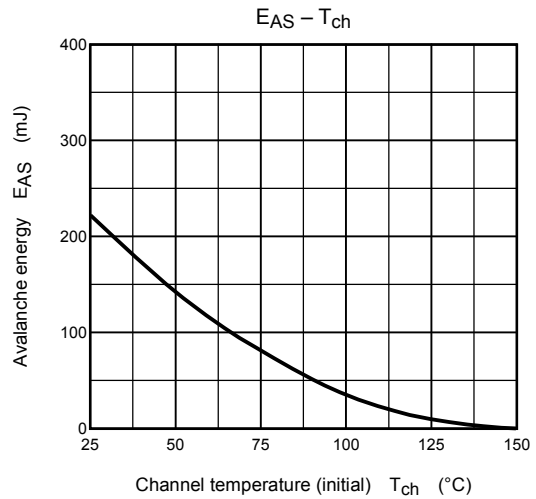
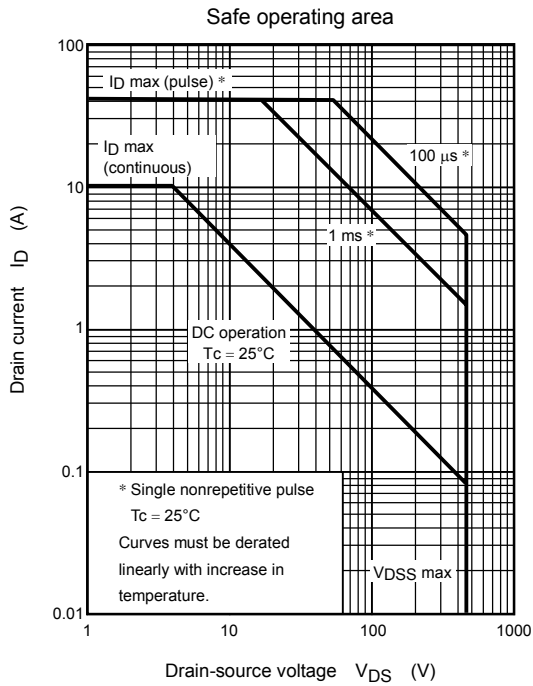
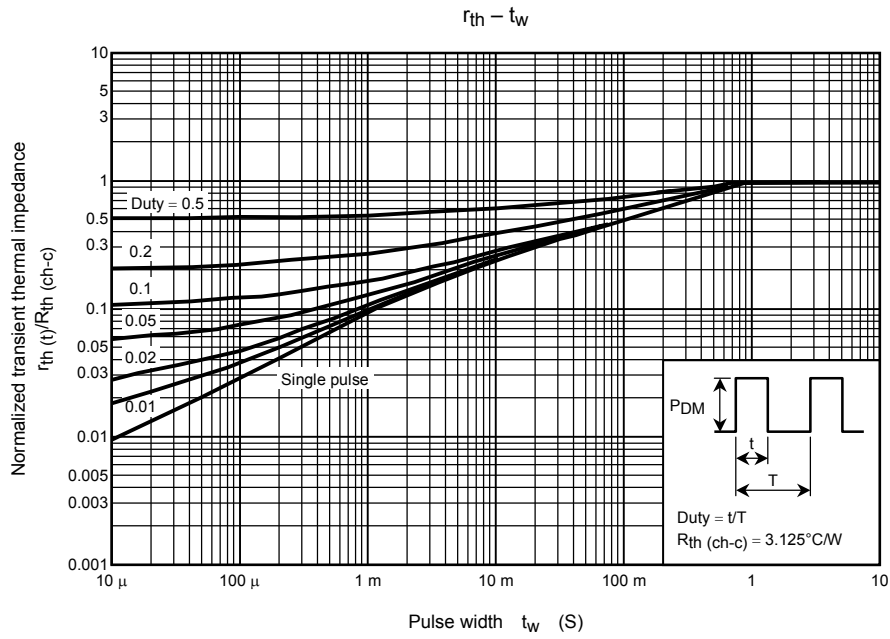
※ Lot Number

□ □ ← Month (starting from alphabet A)

□ ← Year (last number of the christian era)







$R_G = 25 \Omega$
 $V_{DD} = 90 \text{ V}, L = 3.7 \text{ mH}$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I_{AR}^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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